# MICROCHIP

# 25AA080/25LC080/25C080

## 8K SPI™ Bus Serial EEPROM

### Device Selection Table

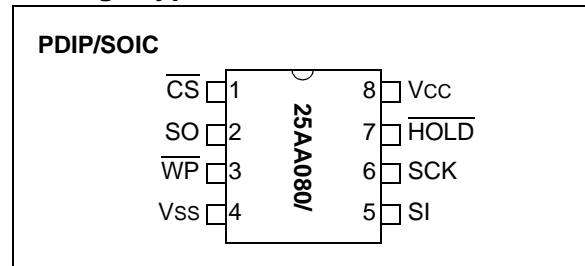| Part Number | Vcc Range | Max. Clock Frequency | Temp. Ranges |
|---|---|---|---|
| 25AA080 | 1.8-5.5V | 1 MHz | I |
| 25LC080 | 2.5-5.5V | 2 MHz | I |
| 25C080 | 4.5-5.5V | 3 MHz | I,E |

### Features:

- Low-power CMOS technology:
  - Write current: 3 mA maximum
  - Read current: 500 μA typical
  - Standby current: 500 nA typical
- 1024 x 8-bit organization
- 16 byte page
- Write cycle time: 5 ms max.
- Self-timed erase and write cycles
- Block write protection:
  - Protect none, 1/4, 1/2 or all of array
- Built-in write protection:
  - Power-on/off data protection circuitry
  - Write enable latch
  - Write-protect pin
- Sequential read
- High reliability:
  - Endurance: 1 M cycles
  - Data retention: > 200 years
  - ESD protection: > 4000V
- 8-pin PDIP and SOIC (150 mil)
- Temperature ranges supported:
  - Industrial (I):  -40°C to +85°C
  - Automotive (E) (25C080):  -40°C to +125°C

*25XX080 is used in this document as a generic part number for the 25AA080/25LC080/25C080 devices.
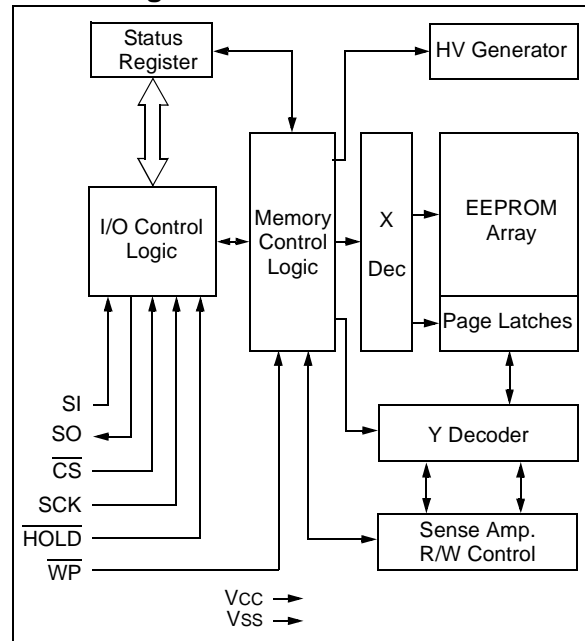
SPI™ is a trademark of Motorola Inc.

### Description:

The Microchip Technology Inc. 25AA080/25LC080/25C080 (25XX080*) are 8 Kbit Serial Electrically Erasable PROMs. The memory is accessed via a simple Serial Peripheral Interface™ (SPI™) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled through a Chip Select (CS) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of chip select, allowing the host to service higher priority interrupts.

### Package Types

**PDIP/SOIC**

```
         ___
    CS  |1      8|  Vcc
    SO  |2      7|  HOLD
    WP  |3  25  6|  SCK
        |  AA080/ |
    Vss |4      5|  SI
```

### Block Diagram

# 25AA080/25LC080/25C080

## 1.0    ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings[†]

VCC.................................................................................................................................................................................7.0V

All inputs and outputs w.r.t. VSS ....................................................................................................... -0.6V to VCC + 1.0V

Storage temperature .................................................................................................................................-65°C to 150°C

Ambient temperature under bias................................................................................................................-40°C to 125°C

Soldering temperature of leads (10 seconds) ...................................................................................................+300°C

ESD protection on all pins................................................................................................................................... 4 KV

> **†** NOTICE: Stresses above those listed under 'Maximum ratings' may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

### 1.1    DC Characteristics

| DC CHARACTERISTICS | | | Industrial (I):    TA = -40°C to +85°C     VCC = 1.8V to 5.5V<br>Automotive (E): TA = -40°C to +125°C    VCC = 4.5V to 5.5V (25C080 only) | | | |
|---|---|---|---|---|---|---|
| Param. No. | Sym. | Characteristic | Min. | Max. | Units | Test Conditions |
| D001 | VIH1 | High-level input voltage | 2.0 | VCC+1 | V | VCC ≥ 2.7V **(Note)** |
| D002 | VIH2 | | 0.7 VCC | VCC+1 | V | VCC< 2.7V **(Note)** |
| D003 | VIL1 | Low-level input voltage | -0.3 | 0.8 | V | VCC ≥ 2.7V **(Note)** |
| D004 | VIL2 | | -0.3 | 0.3 VCC | V | VCC < 2.7V **(Note)** |
| D005 | VOL | Low-level output voltage | — | 0.4 | V | IOL = 2.1 mA |
| D006 | VOL | | — | 0.2 | V | IOL = 1.0 mA, VCC < 2.5V |
| D007 | VOH | High-level output voltage | VCC -0.5 | — | V | IOH = -400 µA |
| D008 | ILI | Input leakage current | -10 | 10 | µA | $\overline{CS}$ = VCC, VIN = VSS TO VCC |
| D009 | ILO | Output leakage current | -10 | 10 | µA | $\overline{CS}$ = VCC, VOUT = VSS TO VCC |
| D010 | CINT | Internal Capacitance (all inputs and outputs) | — | 7 | pF | TA = 25°C, CLK = 1.0 MHz, VCC = 5.0V **(Note)** |
| D011 | ICC Read | Operating Current | —<br>— | 1<br>500 | mA<br>µA | VCC = 5.5V; FCLK = 3.0 MHz; SO = Open<br>VCC = 2.5V; FCLK = 2.0 MHz; SO = Open |
| D012 | ICC Write | | —<br>— | 5<br>3 | mA<br>mA | VCC = 5.5V<br>VCC = 2.5V |
| D013 | ICCS | Standby Current | —<br>— | 5<br>1 | µA<br>µA | $\overline{CS}$ = VCC = 5.5V, Inputs tied to VCC or VSS<br>$\overline{CS}$ = VCC = 2.5V, Inputs tied to VCC or VSS |

**Note:**    This parameter is periodically sampled and not 100% tested.

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## 1.2    AC Characteristics

| AC CHARACTERISTICS | | | | | | Industrial (I):    TA = -40°C to +85°C    VCC = 1.8V to 5.5V<br>Automotive (E):   TA = -40°C to +125°C    VCC = 4.5V to 5.5V (25C080 only) |
|---|---|---|---|---|---|---|
| Param. No. | Sym. | Characteristic | Min. | Max. | Units | Test Conditions |
| 1 | $F_{CLK}$ | Clock Frequency | —<br>—<br>— | 3<br>2<br>1 | MHz<br>MHz<br>MHz | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 2 | $T_{CSS}$ | CS Setup Time | 100<br>250<br>500 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 3 | $T_{CSH}$ | CS Hold Time | 150<br>250<br>475 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 4 | $T_{CSD}$ | CS Disable Time | 500 | — | ns | — |
| 5 | $T_{SU}$ | Data Setup Time | 30<br>50<br>50 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 6 | $T_{HD}$ | Data Hold Time | 50<br>100<br>100 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 7 | $T_R$ | CLK Rise Time | — | 2 | µs | **(Note 1)** |
| 8 | $T_F$ | CLK Fall Time | — | 2 | µs | **(Note 1)** |
| 9 | $T_{HI}$ | Clock High Time | 150<br>230<br>475 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 10 | $T_{LO}$ | Clock Low Time | 150<br>230<br>475 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 11 | $T_{CLD}$ | Clock Delay Time | 50 | — | ns | — |
| 12 | $T_{CLE}$ | Clock Enable Time | 50 | — | ns | — |
| 13 | $T_V$ | Output Valid from Clock Low | —<br>—<br>— | 150<br>230<br>475 | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 14 | $T_{HO}$ | Output Hold Time | 0 | — | ns | **(Note 1)** |
| 15 | $T_{DIS}$ | Output Disable Time | —<br>—<br>— | 200<br>250<br>500 | ns<br>ns<br>ns | VCC = 4.5V to 5.5V **(Note 1)**<br>VCC = 2.5V to 4.5V **(Note 1)**<br>VCC = 1.8V to 2.5V **(Note 1)** |
| 16 | $T_{HS}$ | HOLD Setup Time | 100<br>100<br>200 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 17 | $T_{HH}$ | HOLD Hold Time | 100<br>100<br>200 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 18 | $T_{HZ}$ | HOLD Low to Output High-Z | 100<br>150<br>200 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V **(Note 1)**<br>VCC = 2.5V to 4.5V **(Note 1)**<br>VCC = 1.8V to 2.5V **(Note 1)** |
| 19 | $T_{HV}$ | HOLD High to Output Valid | 100<br>150<br>200 | —<br>—<br>— | ns<br>ns<br>ns | VCC = 4.5V to 5.5V<br>VCC = 2.5V to 4.5V<br>VCC = 1.8V to 2.5V |
| 20 | $T_{WC}$ | Internal Write Cycle Time | — | 5 | ms | — |
| 21 | — | Endurance | 1M | — | E/W Cycles | **(Note 2)** |

**Note 1:**  This parameter is periodically sampled and not 100% tested.

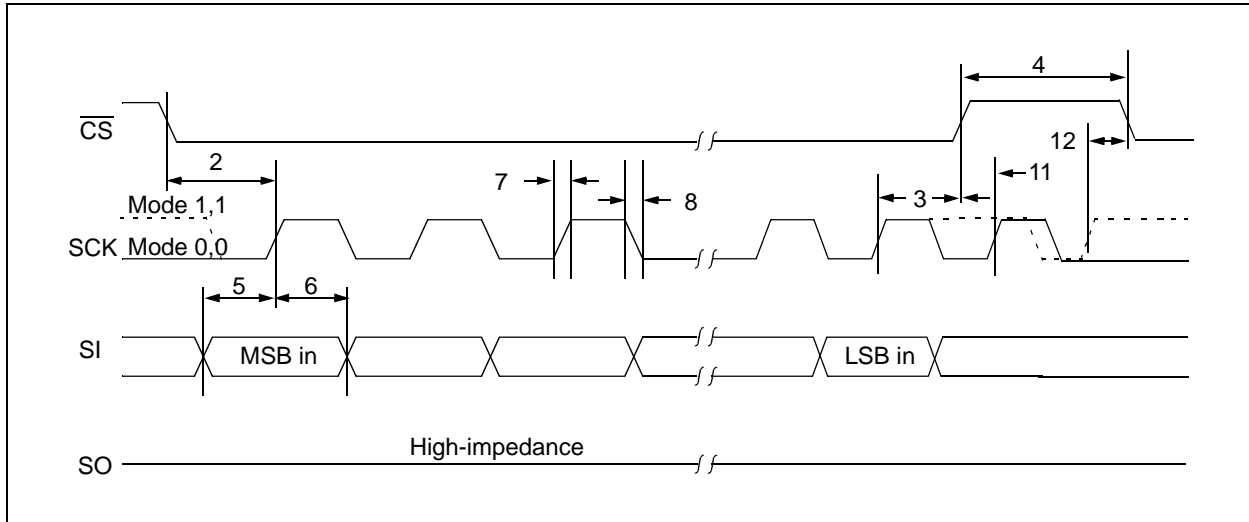**2:**  This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from Microchip's web site at: www.microchip.com.
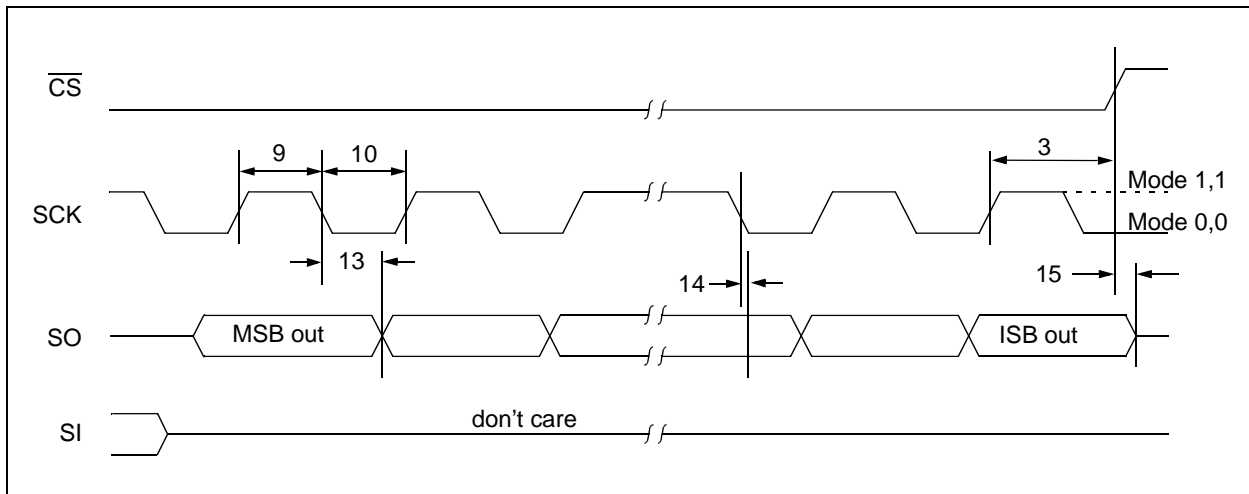
# 25AA080/25LC080/25C080

**FIGURE 1-1:　　HOLD TIMING**
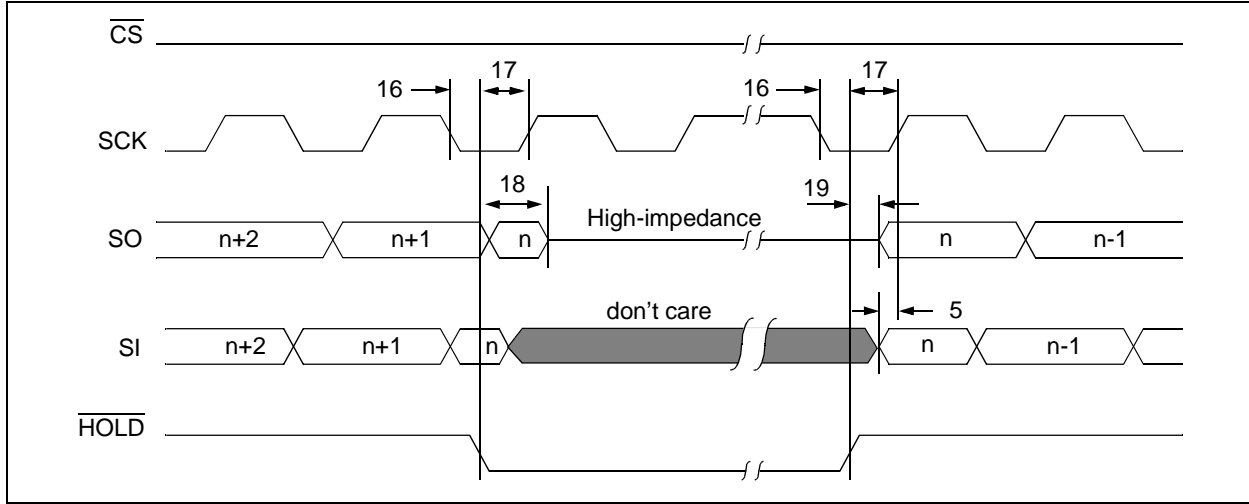


**FIGURE 1-2:　　SERIAL INPUT TIMING**



**FIGURE 1-3:　　SERIAL OUTPUT TIMING**

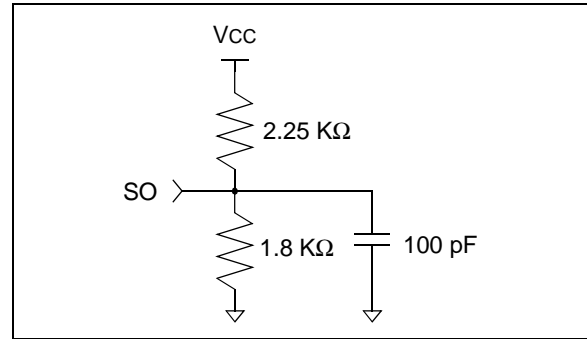© 2004 Microchip Technology Inc.

## 1.3    AC Test Conditions

**AC Waveform:**

| | |
|---|---|
| $V_{LO}$ = 0.2V | — |
| $V_{HI}$ = $V_{CC}$ - 0.2V | **(Note 1)** |
| $V_{HI}$ = 4.0V | **(Note 2)** |
| **Timing Measurement Reference Level** | |
| Input | 0.5 $V_{CC}$ |
| Output | 0.5 $V_{CC}$ |

**Note 1:**  For $V_{CC} \leq 4.0V$

**2:**  For $V_{CC} > 4.0V$

**FIGURE 1-4:**        **AC TEST CIRCUIT**

# 25AA080/25LC080/25C080

## 2.0    PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

**TABLE 2-1:    PIN FUNCTION TABLE**

| Name | PDIP | SOIC | Function |
|------|------|------|----------|
| $\overline{CS}$ | 1 | 1 | Chip Select Input |
| SO | 2 | 2 | Serial Data Output |
| $\overline{WP}$ | 3 | 3 | Write-Protect Pin |
| Vss | 4 | 4 | Ground |
| SI | 5 | 5 | Serial Data Input |
| SCK | 6 | 6 | Serial Clock Input |
| $\overline{HOLD}$ | 7 | 7 | Hold Input |
| Vcc | 8 | 8 | Supply Voltage |

### 2.1    Chip Select ($\overline{CS}$)

A low level on this pin selects the device. A high level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of the $\overline{CS}$ input signal. If $\overline{CS}$ is brought high during a program cycle, the device will go into Standby mode as soon as the programming cycle is complete. When the device is deselected, SO goes to the high-impedance state, allowing multiple parts to share the same SPI bus. A low-to-high transition on $\overline{CS}$ after a valid write sequence initiates an internal write cycle. After power-up, a low level on $\overline{CS}$ is required prior to any sequence being initiated.

### 2.2    Serial Output (SO)

The SO pin is used to transfer data out of the 25XX080. During a read cycle, data is shifted out on this pin after the falling edge of the serial clock.

### 2.3    Write-Protect ($\overline{WP}$)

This pin is used in conjunction with the WPEN bit in the Status register to prohibit writes to the nonvolatile bits in the Status register. When $\overline{WP}$ is low and WPEN is high, writing to the nonvolatile bits in the Status register is disabled. All other operations function normally. When $\overline{WP}$ is high, all functions, including writes to the nonvolatile bits in the Status register operate normally. If the WPEN bit is set, $\overline{WP}$ low during a Status register write sequence will disable writing to the Status register. If an internal write cycle has already begun, $\overline{WP}$ going low will have no effect on the write.

The $\overline{WP}$ pin function is blocked when the WPEN bit in the Status register is low. This allows the user to install the 25XX080 in a system with $\overline{WP}$ pin grounded and still be able to write to the Status register. The $\overline{WP}$ pin functions will be enabled when the WPEN bit is set high.

### 2.4    Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses and data. Data is latched on the rising edge of the serial clock.

### 2.5    Serial Clock (SCK)

The SCK is used to synchronize the communication between a master and the 25XX080. Instructions, addresses or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

### 2.6    Hold ($\overline{HOLD}$)

The $\overline{HOLD}$ pin is used to suspend transmission to the 25XX080 while in the middle of a serial sequence without having to retransmit the entire sequence again. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the $\overline{HOLD}$ pin may be pulled low to pause further serial communication without resetting the serial sequence. The $\overline{HOLD}$ pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high-to-low transition. The 25XX080 must remain selected during this sequence. The SI, SCK and SO pins are in a high-impedance state during the time the device is paused and transitions on these pins will be ignored. To resume serial communication, $\overline{HOLD}$ must be brought high while the SCK pin is low, otherwise serial communication will not resume. Lowering the HOLD line at any time will tri-state the SO line.

## 3.0    FUNCTIONAL DESCRIPTION

### 3.1    Principles of Operation

The 25XX080 are 1024 byte Serial EEPROMs designed to interface directly with the Serial Peripheral Interface (SPI) port of many of today's popular micro-controller families, including Microchip's PIC16C6X/7X microcontrollers. It may also interface with microcontrollers that do not have a built-in SPI port by using discrete I/O lines programmed properly with the software.

The 25XX080 contains an 8-bit instruction register. The device is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The $\overline{CS}$ pin must be low and the $\overline{HOLD}$ pin must be high for the entire operation. The $\overline{WP}$ pin must be held high to allow writing to the memory array.

Table 3-1 contains a list of the possible instruction bytes and format for device operation. All instructions, addresses, and data are transferred MSB first, LSB last.

Data is sampled on the first rising edge of SCK after $\overline{CS}$ goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the $\overline{HOLD}$ input and place the 25XX080 in 'HOLD' mode. After releasing the $\overline{HOLD}$ pin, operation will resume from the point when the $\overline{HOLD}$ was asserted.

### 3.2    Read Sequence

The device is selected by pulling $\overline{CS}$ low. The 8-bit READ instruction is transmitted to the 25XX080 followed by the 16-bit address, with the six MSBs of the address being "don't care" bits. After the correct READ instruction and address are sent, the data stored in the memory at the selected address is shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal address pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (03FFh), the address counter rolls over to address 0000h allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the $\overline{CS}$ pin (Figure 3-1).

### 3.3    Write Sequence

Prior to any attempt to write data to the 25XX080, the write enable latch must be set by issuing the WREN instruction (Figure 3-4). This is done by setting $\overline{CS}$ low and then clocking out the proper instruction into the 25XX080. After all eight bits of the instruction are transmitted, the $\overline{CS}$ must be brought high to set the write enable latch. If the write operation is initiated immediately after the WREN instruction without $\overline{CS}$ being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

Once the write enable latch is set, the user may proceed by setting the $\overline{CS}$ low, issuing a WRITE instruction, followed by the 16-bit address, with the six MSBs of the address being "don't care" bits, and then the data to be written. Up to 16 bytes of data can be sent to the 25XX080 before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page. A page address begins with xxxx xxxx xxxx 0000 and ends with xxxx xxxx xxxx 1111. If the internal address counter reaches xxxx xxxx xxxx 1111 and the clock continues, the counter will roll back to the first address of the page and overwrite any data in the page that may have been written.

For the data to be actually written to the array, the $\overline{CS}$ must be brought high after the Least Significant bit (D0) of the $n^{th}$ data byte has been clocked in. If $\overline{CS}$ is brought high at any other time, the write operation will not be completed. Refer to Figure 3-2 and Figure 3-3 for more detailed illustrations on the byte write sequence and the page write sequence respectively. While the write is in progress, the Status register may be read to check the status of the WPEN, WIP, WEL, BP1 and BP0 bits (Figure 3-6). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

### TABLE 3-1:    INSTRUCTION SET

| Instruction Name | Instruction Format | Description |
|---|---|---|
| READ | 0000 0011 | Read data from memory array beginning at selected address |
| WRITE | 0000 0010 | Write data to memory array beginning at selected address |
| WRDI | 0000 0100 | Reset the write enable latch (disable write operations) |
| WREN | 0000 0110 | Set the write enable latch (enable write operations) |
| RDSR | 0000 0101 | Read Status register |
| WRSR | 0000 0001 | Write Status register |

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**FIGURE 3-1:** **READ SEQUENCE**
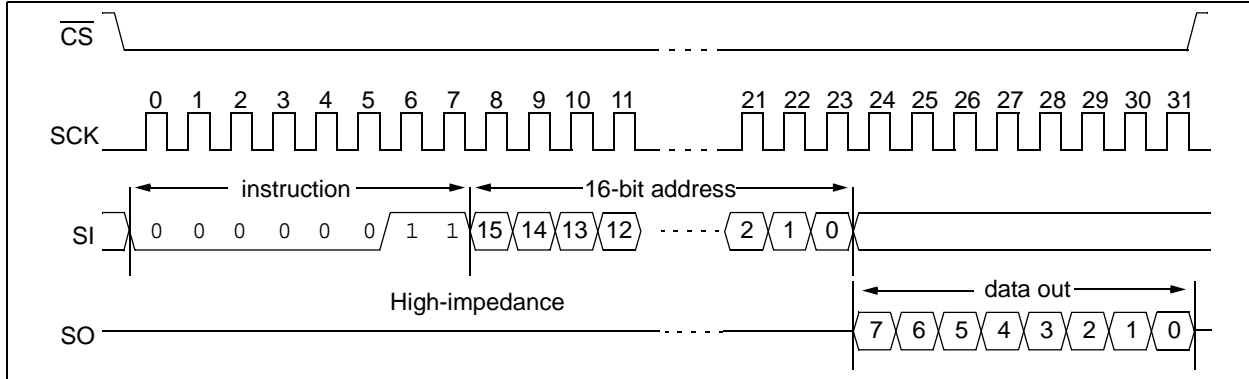


**FIGURE 3-2:** **BYTE WRITE SEQUENCE**
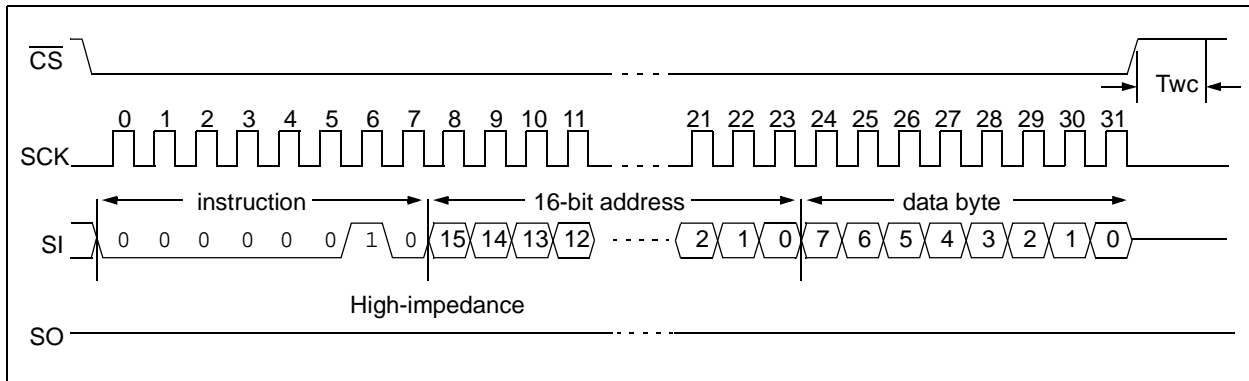


**FIGURE 3-3:** **PAGE WRITE SEQUENCE**
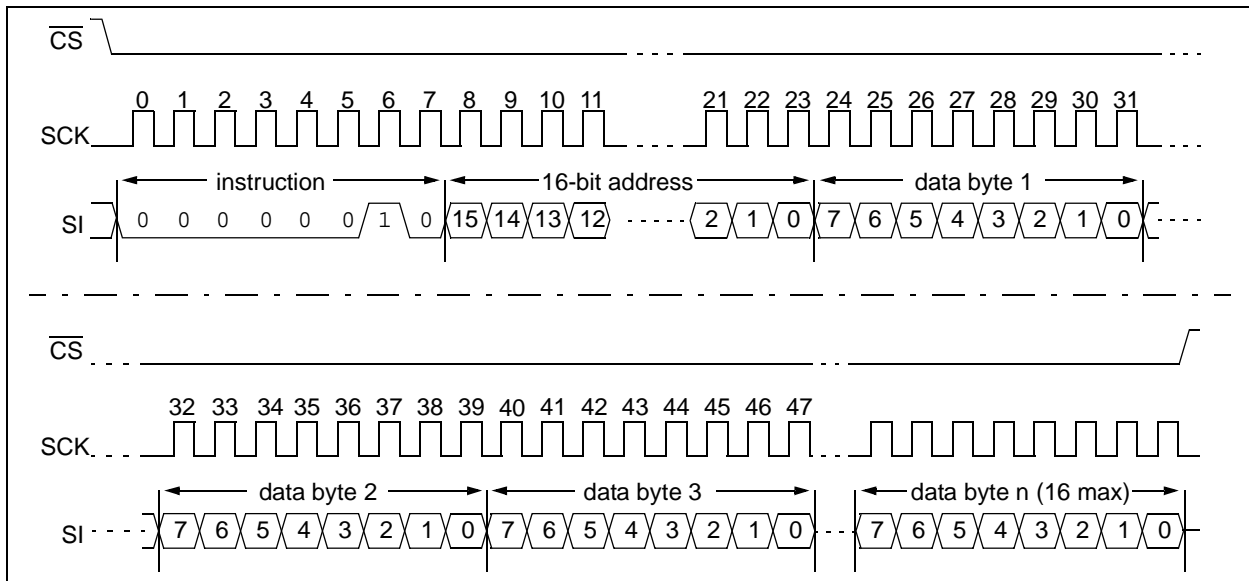
## 3.4 Write Enable (WREN) and Write Disable (WRDI)

The 25XX080 contains a write enable latch. See Table 3-3 for the Write-Protect Functionality Matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch, and the WRDI will reset the latch.
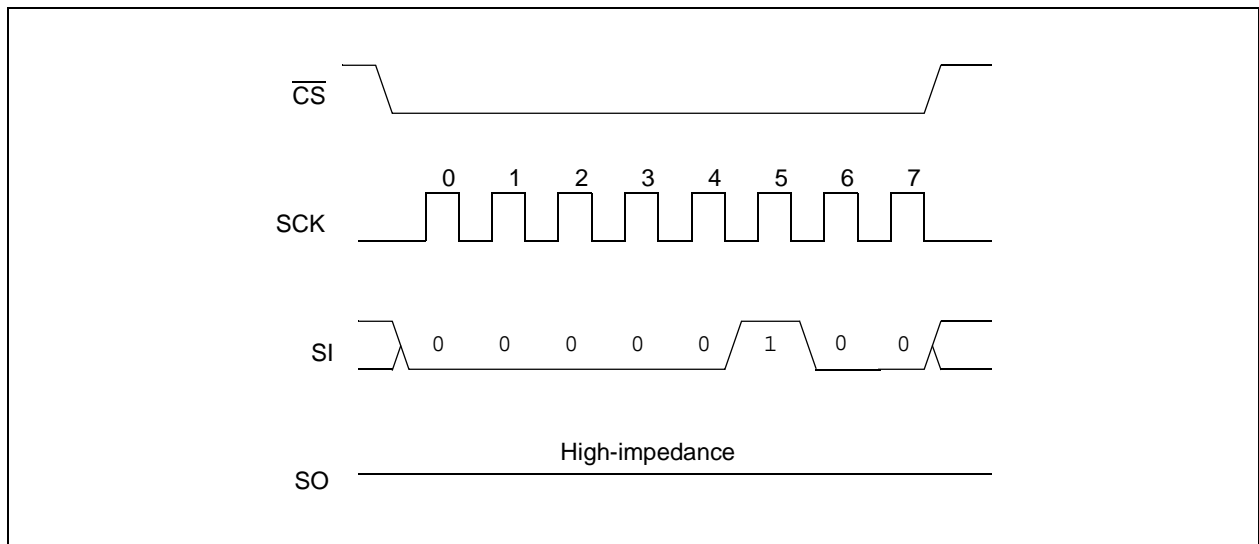
The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed

**FIGURE 3-4: WRITE ENABLE SEQUENCE**
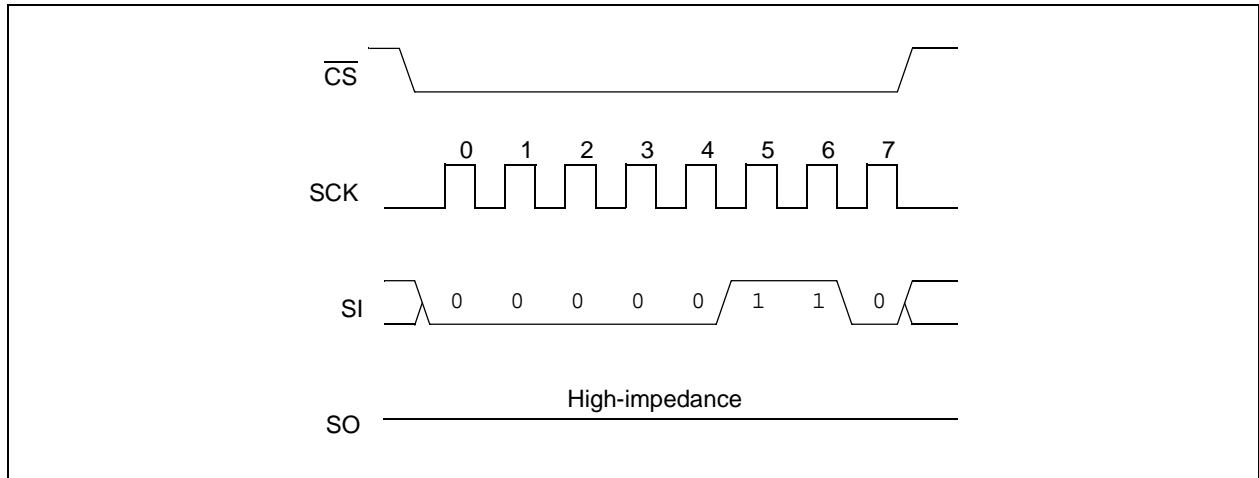


**FIGURE 3-5: WRITE DISABLE SEQUENCE**

## 3.5 Read Status Register (RDSR)

The Read Status Register (RDSR) instruction provides access to the Status register. The Status register may be read at any time, even during a write cycle. The Status register is formatted as follows:

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|---|---|---|-----|-----|-----|-----|
| WPEN | X | X | X | BP1 | BP0 | WEL | WIP |

The **Write-In-Process (WIP)** bit indicates whether the 25XX080 is busy with a write operation. When set to a '1', a write is in progress, when set to a '0', no write is in progress. This bit is read-only.

The **Write Enable Latch (WEL)** bit indicates the status of the write enable latch. When set to a '1', the latch allows writes to the array, when set to a '0', the latch prohibits writes to the array. The state of this bit can always be updated via the WREN or WRDI commands regardless of the state of write protection on the Status register. This bit is read only.

The **Block Protection (BP0 and BP1)** bits indicate which blocks are currently write-protected. These bits are set by the user issuing the WRSR instruction. These bits are nonvolatile.

See Figure 3-6 for the RDSR timing sequence.

**FIGURE 3-6:** READ STATUS REGISTER TIMING SEQUENCE

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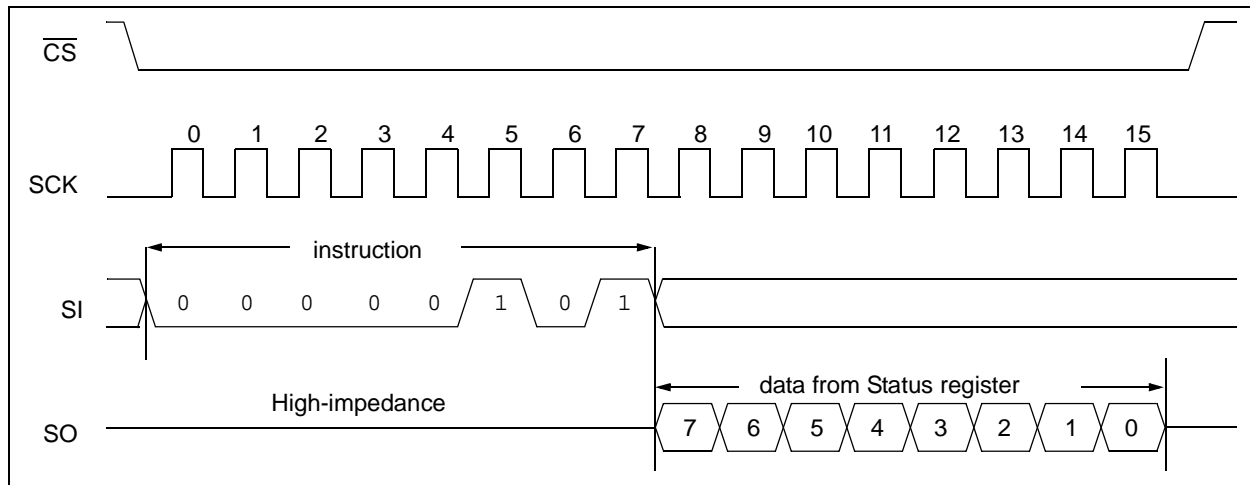
## 3.6 Write Status Register (WRSR)

The Write Status Register (WRSR) instruction allows the user to select one of four levels of protection for the array by writing to the appropriate bits in the Status register. The array is divided up into four segments. The user has the ability to write-protect none, one, two, or all four of the segments of the array. The partitioning is controlled as shown in Table 3-2.

The Write-Protect Enable (WPEN) bit is a nonvolatile bit that is available as an enable bit for the $\overline{WP}$ pin. The Write-Protect ($\overline{WP}$) pin and the Write-Protect Enable (WPEN) bit in the Status register control the programmable hardware write-protect feature. Hardware write protection is enabled when $\overline{WP}$ pin is low and the WPEN bit is high. Hardware write protection is disabled when either the $\overline{WP}$ pin is high or the WPEN bit is low. When the chip is hardware write-protected, only writes to nonvolatile bits in the Status register are disabled. See Table 3-3 for a matrix of functionality on the WPEN bit.

See Figure 3-5 for the WRSR timing sequence.

**TABLE 3-2: ARRAY PROTECTION**

| BP1 | BP0 | Array Addresses Write-Protected |
|-----|-----|--------------------------------|
| 0 | 0 | none |
| 0 | 1 | upper 1/4 (0300h - 03FFh) |
| 1 | 0 | upper 1/2 (0200h - 03FFh) |
| 1 | 1 | all (0000h - 03FFh) |

**FIGURE 3-7: WRITE STATUS REGISTER TIMING SEQUENCE**
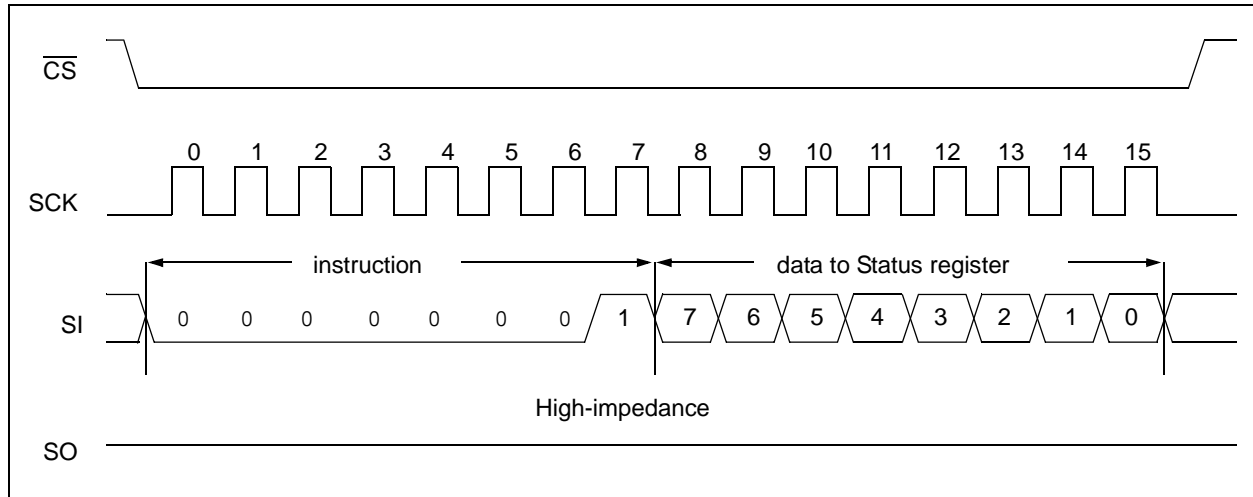
## 3.7 Data Protection

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up
- A `WRITE ENABLE` instruction must be issued to set the write enable latch
- After a byte write, page write or Status register write, the write enable latch is reset
- $\overline{CS}$ must be set high after the proper number of clock cycles to start an internal write cycle
- Access to the array during an internal write cycle is ignored and programming is continued

## 3.8 Power-On State

The 25XX080 powers on in the following state:

- The device is in low-power Standby mode ($\overline{CS}=1$)
- The write enable latch is reset
- SO is in high-impedance state
- A high-to-low level transition on $\overline{CS}$ is required to enter active state
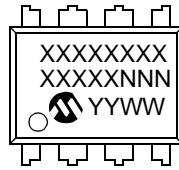
**TABLE 3-3: WRITE-PROTECT FUNCTIONALITY MATRIX**

| WPEN | $\overline{WP}$ | WEL | Protected Blocks | Unprotected Blocks | Status Register |
|------|------|-----|------------------|--------------------|-----------------|
| X | X | 0 | Protected | Protected | Protected |
| 0 | X | 1 | Protected | Writable | Writable |
| 1 | Low | 1 | Protected | Writable | Protected |
| X | High | 1 | Protected | Writable | Writable |

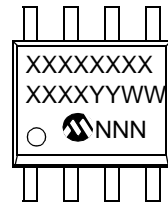## 4.0    PACKAGING INFORMATION

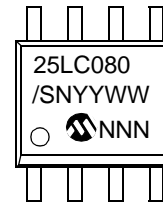### 4.1    Package Marking Information

8-Lead PDIP (300 mil)

```
XXXXXXXX
XXXXXNNN
   YYWW
```

Example:

```
25LC080
/PNNN
   YYWW
```

8-Lead SOIC (150 mil)

```
XXXXXXXX
XXXXYYWW
   NNN
```

Example:

```
25LC080
/SNYYWW
   NNN
```

| Legend: | XX...X | Customer specific information* |
| --- | --- | --- |
| | Y | Year code (last digit of calendar year) |
| | YY | Year code (last 2 digits of calendar year) |
| | WW | Week code (week of January 1 is week '01') |
| | NNN | Alphanumeric traceability code |

**Note**:    In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

\*    Standard PICmicro device marking consists of Microchip part number, year code, week code, and traceability code.  For PICmicro device marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.  For QTP devices, any special marking adders are included in QTP price.

# 25AA080/25LC080/25C080

## 8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)
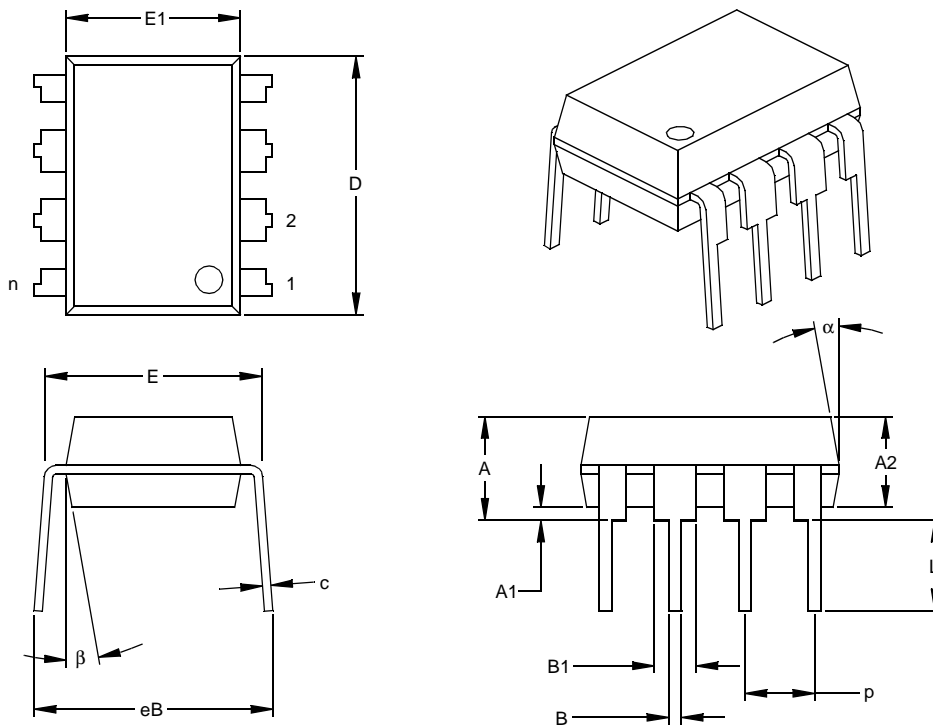


| | Units | INCHES* | | | MILLIMETERS | | |
|---|---|---|---|---|---|---|---|
| Dimension Limits | | MIN | NOM | MAX | MIN | NOM | MAX |
| Number of Pins | n | | 8 | | | 8 | |
| Pitch | p | | .100 | | | 2.54 | |
| Top to Seating Plane | A | .140 | .155 | .170 | 3.56 | 3.94 | 4.32 |
| Molded Package Thickness | A2 | .115 | .130 | .145 | 2.92 | 3.30 | 3.68 |
| Base to Seating Plane | A1 | .015 | | | 0.38 | | |
| Shoulder to Shoulder Width | E | .300 | .313 | .325 | 7.62 | 7.94 | 8.26 |
| Molded Package Width | E1 | .240 | .250 | .260 | 6.10 | 6.35 | 6.60 |
| Overall Length | D | .360 | .373 | .385 | 9.14 | 9.46 | 9.78 |
| Tip to Seating Plane | L | .125 | .130 | .135 | 3.18 | 3.30 | 3.43 |
| Lead Thickness | c | .008 | .012 | .015 | 0.20 | 0.29 | 0.38 |
| Upper Lead Width | B1 | .045 | .058 | .070 | 1.14 | 1.46 | 1.78 |
| Lower Lead Width | B | .014 | .018 | .022 | 0.36 | 0.46 | 0.56 |
| Overall Row Spacing § | eB | .310 | .370 | .430 | 7.87 | 9.40 | 10.92 |
| Mold Draft Angle Top | α | 5 | 10 | 15 | 5 | 10 | 15 |
| Mold Draft Angle Bottom | β | 5 | 10 | 15 | 5 | 10 | 15 |

\* Controlling Parameter
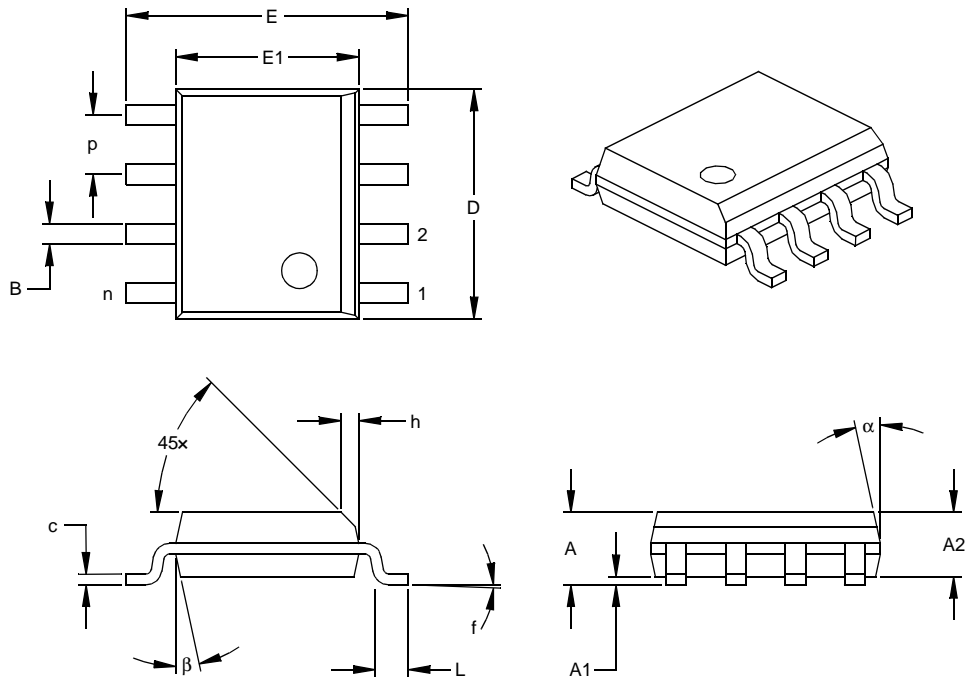§ Significant Characteristic

**Notes:**
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed
.010" (0.254mm) per side.
JEDEC Equivalent:  MS-001
Drawing No. C04-018

## 8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)



| | Units | INCHES* | | | MILLIMETERS | | |
|---|---|---|---|---|---|---|---|
| Dimension Limits | | MIN | NOM | MAX | MIN | NOM | MAX |
| Number of Pins | n | | 8 | | | 8 | |
| Pitch | p | | .050 | | | 1.27 | |
| Overall Height | A | .053 | .061 | .069 | 1.35 | 1.55 | 1.75 |
| Molded Package Thickness | A2 | .052 | .056 | .061 | 1.32 | 1.42 | 1.55 |
| Standoff § | A1 | .004 | .007 | .010 | 0.10 | 0.18 | 0.25 |
| Overall Width | E | .228 | .237 | .244 | 5.79 | 6.02 | 6.20 |
| Molded Package Width | E1 | .146 | .154 | .157 | 3.71 | 3.91 | 3.99 |
| Overall Length | D | .189 | .193 | .197 | 4.80 | 4.90 | 5.00 |
| Chamfer Distance | h | .010 | .015 | .020 | 0.25 | 0.38 | 0.51 |
| Foot Length | L | .019 | .025 | .030 | 0.48 | 0.62 | 0.76 |
| Foot Angle | f | 0 | 4 | 8 | 0 | 4 | 8 |
| Lead Thickness | c | .008 | .009 | .010 | 0.20 | 0.23 | 0.25 |
| Lead Width | B | .013 | .017 | .020 | 0.33 | 0.42 | 0.51 |
| Mold Draft Angle Top | α | 0 | 12 | 15 | 0 | 12 | 15 |
| Mold Draft Angle Bottom | β | 0 | 12 | 15 | 0 | 12 | 15 |

\* Controlling Parameter
§ Significant Characteristic

**Notes:**
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed
.010" (0.254mm) per side.
JEDEC Equivalent: MS-012
Drawing No. C04-057

## APPENDIX A:   REVISION HISTORY

**Revision D**

Added note to page 1 header (Not recommended for new designs).

Updated document format.

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042003

# 25AA080/25LC080/25C080

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    _____

    _____

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    _____

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    _____

    _____

4. What additions to the document do you think would enhance the structure and subject?

    _____

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    _____

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    _____

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To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

| PART NO. | X | /XX | XXX |
|---|---|---|---|
| Device | Temperature Range | Package | Pattern |

Device

25AA080: 8 Kbit 1.8V SPI Serial EEPROM
25AA080T: 8 Kbit 1.8V SPI Serial EEPROM (Tape and Reel)
25LC080: 8 Kbit 2.5V SPI Serial EEPROM
25LC080: 8 Kbit 2.5V SPI Serial EEPROM (Tape and Reel)
25C080: 8 Kbit 5.0V SPI Serial EEPROM
25C080: 8 Kbit 5.0V SPI Serial EEPROM (Tape and Reel)

Temperature Range

I $= -40°C$ to $+85°C$
E $= -40°C$ to $+125°C$

Package

P $=$ Plastic DIP (300 mil body), 8-lead
SN $=$ Plastic SOIC (150 mil body), 8-lead

**Examples:**

a) 25AA080-I/SN: Industrial Temp., SOIC package

b) 25AA080T-I/SN: Tape and Reel, Industrial Temp., SOIC package

c) 25LC080-I/SN: Industrial Temp., SOIC package

d) 25LC080T-I/SN: Tape and Reel, Industrial Temp., SOIC package

e) 25C080-I/P: Industrial Temp., PDIP package

f) 25C080-I/SN: Industrial Temp., SOIC package

g) 25C080T-I/SN: Tape and Reel, Industrial Temp., SOIC package

h) 25C080-E/SN: Extended Temp., SOIC package

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